

## INCHANGE SEMICONDUCTOR

## isc N-Channel MOSFET Transistor

## FMV12N50E

### FEATURES

- With TO-220F packaging
- High speed switching
- Very high commutation ruggedness
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operationz

### APPLICATIONS

- Switching applications
- DC-DC converters
- Uninterruptible power supply

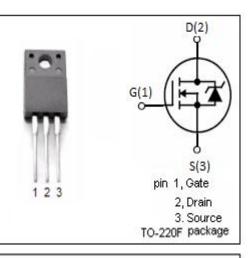
### • ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

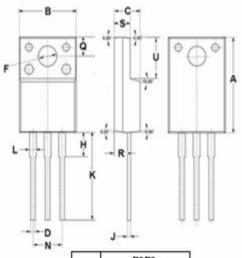
SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	500	V
V <sub>GSS</sub>	Gate-Source Voltage	±30	V
ID	Drain Current-Continuous	12	А
I <sub>DM</sub>	Drain Current-Single Pulsed	48	A
PD	Total Dissipation	60	W
Tj	Operating Junction Temperature	-55~150	°C
T <sub>stg</sub>	Storage Temperature	-55~150	°C

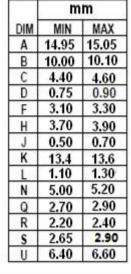
### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	2.1	°C <b>/W</b>	
Rth(ch-a)	Channel-to-ambient thermal resistance	58	°C/W	

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## **ELECTRICAL CHARACTERISTICS**

#### $T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	500			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =±30V; I <sub>D</sub> =0.25mA	2.5		3.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =6A		445	520	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 500V; V <sub>GS</sub> = 0V;Tc=25°C V <sub>DS</sub> = 400V; V <sub>GS</sub> = 0V;Tc=125°C			25 250	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =12A, V <sub>GS</sub> = 0 V			1.32	V

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